Diodes

Structure. Symbol Diode - semiconductor device

Physical structure



The **pn** junction - an interface between two types of semiconductor materials, *p*-type and *n*-type.

In the outer shells of the electrically neutral atoms:

- \circ the *p* (positive) side contains an excess of holes (positive charges)
- the *n* (negative) side contains an excess of electrons (negative charges)

The *pn* junction is created by **doping**:

- \checkmark p-type doping an intrinsic semiconductor (e.g. Si) is doped with acceptor impurities (column 3 in the periodic table \rightarrow excess of holes
- \checkmark *n*-type doping an intrinsic semiconductor (e.g. Si) is doped with donor impurities (column 5 in the periodic table \rightarrow excess of electrons

A pn junction diode allows electric charges to flow only in one direction:

- negative charges (electrons) can flow through the junction from n to p but not from p to n,
- positive charges (holes) can flow through the junction from *p* to *n* but not from *n* to *p*,



When the *pn* junction is forward-biased, electric charge flows freely due to reduced resistance of the *pn* junction. When the p–n junction is reverse-biased, the junction barrier (and therefore resistance) becomes greater and charge flow is minimal (zero).



Circuit symbol

Positive directions for current and voltage





The arrow in the diode's symbol points in the direction of forward current flow.

Current – voltage characteristic

The current flowing through the diode is controlled by the voltage drop across the diode itself – **nonlinear semiconductor device**

Shockley diode equation (diffusion equation)

$$i_D = I_S (e^{\frac{v_D}{nV_T}} - 1) \approx I_S e^{\frac{v_D}{nV_T}}$$

 I_S - saturation current (~ nA - pA) depends on temperature i_D depends exponentialy on v_D

$$V_{T} = \frac{KT}{q}$$
 thermal voltage (depends on temperature)

$$V_{T} = 25 \text{ mV } @ 20^{\circ} \text{ C}$$

$$q - \text{ elementary charge (electric charge carried by a single electron)}$$

$$T - \text{ absolute temperature measured in K degrees}$$

$$n - ideality factor (emission coefficient)$$

n = 2 discrete diodes

n = 1 integrated diodes



Illustration



D is a rectifier diode, 1N400x with I_s =14nA, n = 2

Assuming a voltage drop across the diode in conduction

 $v_D = 0.7$ V = 700 mV

$$V_T = 25 \,\mathrm{mV} @ 20^{\circ} \mathrm{C}$$

the current through the diode results as:

$$i_D = 14 \cdot 10^{-9} \cdot e^{\frac{700}{2 \cdot 25}} = 16.8 \text{mA}$$

Operating (quiescent) point $Q(V_D; I_D)$

Illustration for 1N400x with I_s =14nA, n=2



Temperature dependence

 $i_D \cong I_S e^{\frac{\cdot D}{nV_T}}$





At a constant current the voltage across the diode decreases by approximately 2 mV for every 1°C increase in temperature.

Negative tempco

 $TC = -2mV/{}^{\circ}C$

 20°C $v_D = 650 \,\text{mV}$

 $40^{\circ} C \qquad v_D = 610 \,\mathrm{mV}$

$$v_D(T_2) = v_D(T_1) + TC \cdot (T_2 - T_1) \Big|_{I_D - cst}$$

At a constant voltage across the diode the current increases with the temperature

 V_{D2} V_{D1}

 $T_2 > T_1$

Determining the operating point

□ Circuit with a dc voltage source and a resistor



 \Rightarrow Transcendental equation

Two solving methods:

- **1. Graphical method**
- 2. Numerical method (successive approximation)



Numerical analysis - simplified

If V_I high enough, the D is on; (else D is off)

Assume the voltage drop across the conducting diode $V_D = 0.7V$ and compute the current I_D using the load line (circuit) equation

Circuit equation: $V_I = I_D R + V_D$



Illustration



 $V_I = 9V, R = 0.5K\Omega$

a) What is the operating(quiescent) point of the diode *D*?



 V_D high enough

Assume $V_D = 0.7 \text{V}$ across the conducting diode

$$I_D = \frac{V_I - V_D}{R}$$
 $I_D = \frac{9 - 0.7}{0.5} = 16.6 \text{mA}$



Numerical analysis - iteratively

1. Consider an initial value of diode voltage, eg. $V_D^{(0)} = 0.7V$ and **compute** the current $I_D^{(0)}$ using the load line equation.

 $(V_D^{(0)}, I_D^{(0)})$ – initial solution

2. With $I_D^{(0)}$ compute the diode voltage from **diode equation**, then the current $I_D^{(1)}$ from load line equation

 $(V_D^{(1)}, I_D^{(1)})$ – solution after first iteration

We finalize one iteration. If a more accurate solution is necessary, further iteration should be performed.

For quick, first order analysis of the circuit, usually the initial solution is considered!

Illustration





Consider V_I =3V, R=0.5K Ω , D is 1N400x with I_S =14nA and n=2. What is the operating (quiescent) point of the diode?

Quick, first order analysis:

 $V_D > 0.6$ V D - (on)

Assume $V_D = 0.7$ V in conduction

$$I_D = \frac{V_I - V_D}{R}$$
 $I_D = \frac{3 - 0.7}{0.5} = 4.6 \text{mA}$ $Q(0.7 \text{V}, 4.6 \text{mA})$

Detailed analysis:

$$I_D = \frac{V_I - V_D}{R} \qquad V_D = nV_T \ln \frac{I_D}{I_S}$$

$$V_D^{(0)} = 0.7V$$

$$I_D^{(0)} = \frac{3 - 0.7}{0.5} = 4.6 \text{ mA}$$

$$Q^{(0)}(0.7V, 4.6 \text{ mA})$$

OPTIONAL

$$V_D^{(1)} = nV_T \cdot \ln \frac{I_D^{(0)}}{I_s} = 2 \cdot 0.025 \cdot \ln \frac{4.6\text{mA}}{14\text{nA}} = 0.635\text{V}$$
$$I_D^{(1)} = \frac{V_I - V_D^{(1)}}{R} = \frac{3 - 0.635}{0.5} = 4.73\text{mA}$$
$$Q^{(1)}(0.635\text{V}, 4.73\text{mA})$$

$$V_D^{(2)} = n \cdot V_T \cdot \ln \frac{I_D^{(1)}}{I_S} = 2 \cdot 0.025 \cdot \ln \frac{4.73 \text{mA}}{14 \text{nA}} = 0.637 \text{V}$$
$$I_D^{(2)} = \frac{V_I - V_D^{(2)}}{R} = \frac{3 - 0.637}{0.5} = 4.726 \text{mA}$$
$$Q^{(2)}(0.637 \text{V}, 4.726 \text{mA})$$



If $v_D < 0.7V$ D - (off) If v_D tends to be > 0.7V D - (on)



 $\begin{cases} v_D < 0.7 \\ i_- = 0 \end{cases}$

 $\xrightarrow{\mathbf{0}. / \mathbf{v}} K$

 $\begin{cases} v_D = 0.7 \mathrm{V} \\ i_D > 0 \end{cases}$

DR two-port networks analysis



VTC – voltage transfer characteristic

- 1. Consider **all possible situations** resulting from the combination of the **diode states** (*on*, *off*)
- 2. For each situation :
 - i. draw the equivalent circuit
 - ii. find v_O
 - iii. determine the range of v_I for that particular situation
- 3. Draw *VTC*.

Example

What is the VTC $v_O(v_I)$?



Example - cont

What is the VTC $v_O(v_I)$?





$$v_D < 0.7 V \quad i_D = 0$$
$$v_O = 0$$

$$D - (on)$$

$$A = 0.7V K$$

$$v_{I} \downarrow O$$

$$i_{D} > 0$$

$$v_{D} = 0.7V$$

$$i_{D} > 0$$

$$v_{D} = 0.7V$$

$$V_{O} = v_{I} - v_{D} = v_{I} - 0.7V$$

$$v_D = v_I - v_O$$

 $v_I < 0.7V$ $i_D = \frac{v_O}{R} = \frac{v_I - 0.7V}{R}$ $v_I > 0.7V$



Waveforms for a voltage rectifier





 $v_{O}(t) = ?$

Waveforms for a voltage rectifier





The influence of the threshold voltage and voltage drop across the diode in conduction



• If the input voltage is large enough (>> 0.7V)

- the threshold voltage can be neglected (considered 0V)
- the voltage drop across the conducting diode can be neglected; $D (\text{on}); v_0 = v_I$

Applications of DR two-port networks

Half-wave rectifier



13.4

The difference in voltage between the primary and the secondary windings is achieved by changing the number of coil turns in the primary winding compared to the number of coil turns on the secondary winding.















 $\begin{cases} v_A > v_B \\ v_A > 0.7 V \end{cases} \quad D_1 - (on), \ D_2 - (off); \ v_O = v_A - 0.7 V \end{cases}$

$$\begin{cases} v_B > v_A \\ v_B > 0.7 V \end{cases} \quad D_1 - (off), \ D_2 - (on); \quad v_O = v_B - 0.7 V \end{cases}$$

 $\begin{cases} v_A < 0.7V \\ v_B < 0.7V \end{cases} \quad D_1 - (off), \ D_2 - (off); \ v_O = 0 \\ v_O = \max(v_A - 0.7V; v_B - 0.7V; 0V) \end{cases}$



$$v_{O} = \max(v_{A} - 0.7\text{V}; v_{B} - 0.7\text{V}; 0)$$

 $v_{O} = \max(v_{A}; v_{B}; 0)$ neglecting 0.7V

----- neglecting 0.7V ---- D - constant-voltage-drop

What is the peak value of the current through each circuit element if $R=5k\Omega$?

What is the range of values for *R*, if the peak forward current through diode is 200mA?





DR logic circuits

analog signal



* two-input OR circuit



 $\begin{array}{l} 0V \rightarrow logic \ 0 \\ 5V \rightarrow logic \ 1 \end{array}$

v_A	v_{B}	v_Y	D_1	D_2
0V	0V	0V	(off)	(off)
0V	5V	4.3V	(off)	(on)
5V	0V	4.3V	(on)	(off)
5V	5V	4.3V	(on)	(on)

operating table

A	В	Y		
0	0	0		
0	1	1		
1	0	1		
1	1	1		

truth table

* three-input AND circuit

 $\begin{array}{l} 0V \rightarrow logic \ 0 \\ 5V \rightarrow logic \ 1 \end{array}$



$v_{A}[V]$	$v_{B}[V]$	$\mathbf{v}_{C}[V]$	$v_{Y}[V]$	А	В	С	Υ
0	0	0	0.7	0	0	0	0
0	0	5	0.7	0	0	1	0
0	5	0	0.7	0	1	0	0
0	5	5	0.7	0	1	1	0
5	0	0	0.7	1	0	0	0
5	0	5	0.7	1	0	1	0
5	5	0	0.7	1	1	0	0
5	5	5	5	1	1	1	1

operating table

truth table

Full wave rectifierdiode bridge

neglecting 0.7V across the conducting diode





> positive half, $v_I > 0$ $D_1, D_3 - (\text{on}) D_2, D_4 - (\text{off})$

> > negative half, $v_I < 0$ $D_1, D_3 - (off) D_2, D_4 - (on)$



Problem



For the circuit in the figure, $R_L = 50\Omega$. Assume $\hat{V}_I = 25V$

- a) $v_O(t)$ and $i_O(t)$
- b) What are the value of the maximum reverse voltage v_{DR} across each diode and the maximum forward current through each diode?
- c) Repeat a) and b) assuming $\hat{V}_I = 6.4$ V

Power-supply filtering

 v_I is the voltage in a secondary winding of a step-down line transformer.

It is required to obtain an almost dc voltage (on a load resistor)



How "to smooth" the output voltage (as close as possible to dc)?

Power-supply filtering - cont.

1st step

Half-wave (full wave) rectifier



How "to smooth" the output voltage (as close as possible to dc)?



Between successive peeks of input voltage (and rectified voltage), D - *off*, the capacitor acts as a element of electrical energy storage, providing electrical energy in the load, with a decrease of its own voltage.



If the **current** through the capacitor, can be approximated as being a **constant** one *I*_{*C*}:

$$v_{c(t)} = \frac{1}{C} I_C(t - t_0) + v_c(t_0)$$

$$v_{c(t)} - v_c(t_0) = \frac{1}{C} I_C(t - t_0)$$

$$\Delta v_c = \frac{1}{C} I_C \Delta t$$

$$C \Delta v_c(t) = i_C(t) dt$$

$$C \Delta v_c = I_C \Delta t$$
For I_C constant



Between successive peeks of input voltage (and rectified voltage), **D** - *off*, the capacitor acts as a element of electrical energy storage, providing electrical energy in the load, with a decrease of its own voltage:

C discharges through *R*; the discharging current is supposed to be constant, to its maximum value.

$$\Delta v_c = \frac{1}{C} I_C \Delta t$$

$$I_c = \frac{\hat{V}_o}{R}$$

$$\Delta t = t_d = T - t_c \approx T$$

$$\Delta v_c = \Delta v = \frac{1}{C} I_C \Delta t = \frac{1}{C} \frac{\hat{V}_o}{R} T$$

$$\Delta v = \hat{V}_o \frac{T}{RC} = \frac{1}{f} \frac{\hat{V}_o}{RC}$$

RC – time constant of the circuit

Example

 $\hat{V}_I = 10.7 \text{V}$ f = 50 Hz $R_L = 100 \Omega$ $\Delta v < 1.5 \text{V}$ **C=?**



We chose an electrolytic capacitor $C = 1500 \mu F/25V$ What is the actual value of the output ripple? What should be a new value of *C* if the output ripple must be reduce to the half? Solve again in the case of full-wave rectification.